



ELECTRONICS, INC.

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## NTE7155 Integrated Circuit Dual Low-Voltage Power Amplifier

### Description:

The NTE7155 is a monolithic integrated circuit in an 8-Lead DIP type package designed for use as a dual audio power amplifier in portable cassette players and radios.

### Features:

- Supply Voltage Down To 1.8V
- Low Crossover Distortion
- Low Quiescent Current
- Bridge or Stereo Configuration

### Absolute Maximum Ratings:

Supply Voltage, $V_S$ .....	15V
Peak Output Current, $I_O$ .....	1A
Total Power Dissipation, $P_D$	
$T_A = +50^\circ\text{C}$ .....	1.0W
$T_C = +50^\circ\text{C}$ .....	1.4W
Operating Junction Temperature Range, $T_J$ .....	$-40^\circ$ to $+150^\circ\text{C}$
Storage Temperature Range, $T_{stg}$ .....	$-40^\circ$ to $+150^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient, $R_{thJA}$ .....	100°C/W
Thermal Resistance, Junction-to-Case (Pin4), $R_{thJC}$ .....	70°C/W

### Electrical Characteristics: ( $V_S = 6V$ , $T_A = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Stereo</b>						
Supply Voltage	$V_S$		1.8	–	15	V
Quiescent Output Voltage	$V_O$		–	2.7	–	V
		$V_S = 3V$	–	1.2	–	V
Quiescent Drain Current	$I_D$		–	6	9	mA
Input Bias Current	$I_B$		–	100	–	nA

**Electrical Characteristics (Cont'd):** ( $V_S = 6V$ ,  $T_A = +25^\circ C$  unless otherwise specified)

Parameter	Symbol	Test Conditions		Min	Typ	Max	Unit
<b>Stereo (Cont'd)</b>							
Output Power (Each Channel) ( $f = 1kHz$ , $d = 10\%$ )	$P_O$	$R_L = 32\Omega$	$V_S = 9V$	–	300	–	mW
			$V_S = 6V$	90	120	–	mW
			$V_S = 4.5V$	–	60	–	mW
			$V_S = 3V$	15	20	–	mW
			$V_S = 2V$	–	5	–	mW
		$R_L = 16\Omega$	$V_S = 6V$	170	220	–	mW
		$R_L = 8\Omega$	$V_S = 9V$	–	1000	–	mW
			$V_S = 6V$	300	380	–	mW
		$R_L = 4\Omega$	$V_S = 6V$	450	650	–	mW
			$V_S = 4.5V$	–	320	–	mW
$V_S = 3V$	–		110	–	mW		
Distortion ( $f = 1kHz$ )	$d$	$R_L = 32\Omega$ , $P_O = 40mW$		–	0.2	–	%
		$R_L = 16\Omega$ , $P_O = 75mW$		–	0.2	–	%
		$R_L = 8\Omega$ , $P_O = 150mW$		–	0.2	–	%
Closed Loop Voltage Gain	$G_V$	$f = 1kHz$		36	39	41	dB
Channel Balance	$\Delta G_V$			–	–	$\pm 1$	dB
Input Resistance	$R_I$	$f = 1kHz$		100	–	–	k $\Omega$
Total Input Noise	$e_N$	$R_S = 10k\Omega$	$B = \text{Curve A}$	–	2.0	–	$\mu V$
			$B = 22Hz \text{ to } 22kHz$	–	2.5	–	$\mu V$
Supply Voltage Rejection	SVR	$f = 100Hz$ , $C_1 = C_2 = 100\mu F$		24	30	–	dB
Channel Separation	$C_S$	$f = 1kHz$		–	50	–	dB
<b>Bridge</b>							
Supply Voltage	$V_S$			1.8	–	15	V
Quiescent Drain Current	$I_D$	$R_L = \infty$		–	6	9	mA
Output Offset Voltage (Between Outputs)	$V_{OS}$	$R_L = 8\Omega$		–	–	$\pm 50$	mV
Input Bias Current	$I_B$			–	100	–	nA
Output Power ( $f = 1kHz$ , $d = 10\%$ )	$P_O$	$R_L = 32\Omega$	$V_S = 9V$	–	1000	–	mW
			$V_S = 6V$	320	400	–	mW
			$V_S = 4.5V$	–	200	–	mW
			$V_S = 3V$	50	65	–	mW
			$V_S = 2V$	–	8	–	mW
		$R_L = 16\Omega$	$V_S = 9V$	–	2000	–	mW
			$V_S = 6V$	–	800	–	mW
			$V_S = 3V$	–	120	–	mW
		$R_L = 8\Omega$	$V_S = 6V$	900	1350	–	mW
			$V_S = 4.5V$	–	700	–	mW
			$V_S = 3V$	–	220	–	mW
		$R_L = 4\Omega$	$V_S = 4.5V$	–	1000	–	mW
			$V_S = 3V$	200	350	–	mW
			$V_S = 2V$	–	80	–	mW

**Electrical Characteristics (Cont'd):** ( $V_S = 6V$ ,  $T_A = +25^\circ C$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit	
<b>Bridge (Cont'd)</b>							
Distortion	d	$R_L = 8\Omega$ , $P_O = 0.5W$ , $f = 1kHz$	–	0.2	–	%	
Closed Loop Voltage Gain	$G_V$	$f = 1kHz$	–	39	–	dB	
Input Resistance	$R_I$	$f = 1kHz$	100	–	–	$k\Omega$	
Total Input Noise	$e_N$	$R_S = 10k\Omega$	B = Curve A	–	2.5	–	$\mu V$
			B = 22Hz to 22kHz	–	3.0	–	$\mu V$
Supply Voltage Rejection	SVR	$f = 100Hz$	–	40	–	dB	
Power bandwidth (–3dB)	B	$R_L = 8\Omega$ , $P_O = 1W$	–	120	–	kHz	

**Pin Connection Diagram**

